

Based on Magtron Quadracore ASIC Solution



## Features

- ◆ Ultra small packaging
- ◆ Magtron Quadracore technology
- ◆ Open loop programmable solution
- ◆ Single 5V supply voltage
- ◆ Printed circuit board mounting
- ◆ Casing and materials UL-listed
- ◆ Appearance patented
- ◆ Stable accuracy
- ◆ Low temperature coefficient
- ◆ High immunity to external interference
- ◆ Programmable analog output
- ◆ Low insertion loss
- ◆ Integration frequency filter
- ◆ Easy to mount with automatic handling system

## Applications

- ◆ Inverter and Servo
- ◆ Home appliance
- ◆ Shunt solution replacement
- ◆ Uninterruptible Power Supply

## Standards

- ◆ EN50178 : 1997
- ◆ IEC61010-1 : 2010
- ◆ UL508 : 2010

## Select Part List

Part Number	Primary current measuring range	Accuracy	Quantity/Carton
MS20A	20A	3%	480 pcs
MS20B	20A	5%	480 pcs

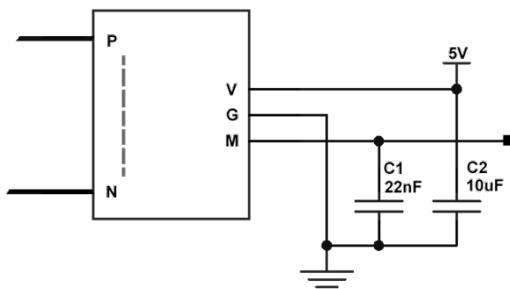
## Overview

The MS series device is a high performance current sensor based on Magtron ASIC Quadracore technology with high accuracy in the full temperature range, adjustable analog output.

It's suitable for the application of industrial products, such as the inverter, UPS, servo motor driver and other industrial products. The ultra-small package is designed for the high power density application and easy to use.

MS series is designed for the replacement of shunt solution and the transformer solution with high cost effective.

## Application circuit



Note: C1, C2 should be close to the current sensor's pin

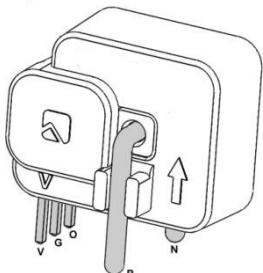
Component selection reference:

Designator	Description
C1	TDK,X7R,22nF/16V,±10%,0603
C2	TDK,X5R,10uF/16V,±10%,0603

## Pin Definition

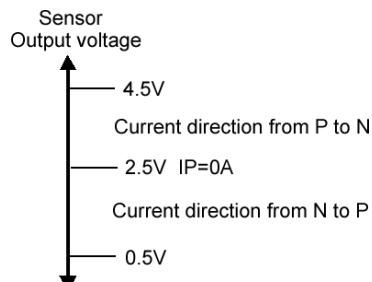
Symbol	Description
V	Power supply pin
G	Power GND pin
O	Signal output pin

## Assembly PIN output:



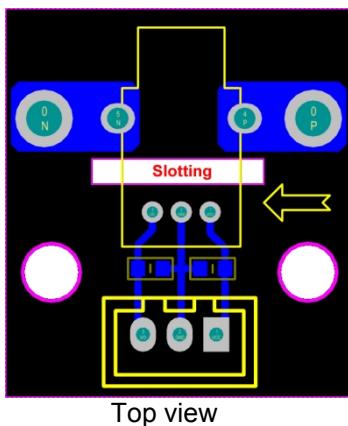
① N,P: The primary side Pin

② V,G,O: Secondary side Pin



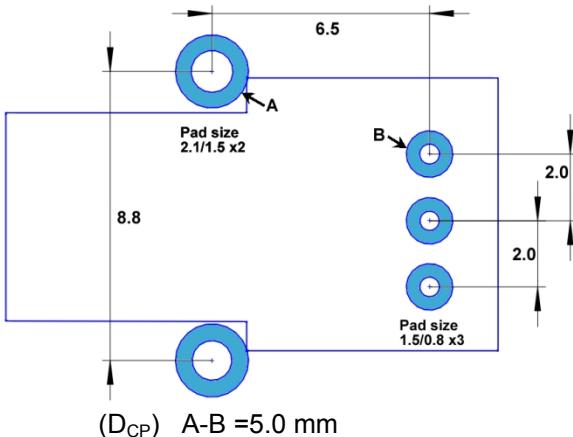
Relationship between IP and output voltage

## MS Demo board PCB Layout Reference



Top view

## MS20 Series, PCB Footprint (in mm. Tolerance ±0.2mm )



**Absolute Maximum Ratings**

Parameter	Symbol	Min	Typ	Max	Unit
Supply Voltage(not operating)	V <sub>C</sub>			9	V
Jumper temperature	T <sub>J</sub>		120		
Ambient operating temperature	T <sub>A</sub>	-40		+85	
Ambient storage temperature	T <sub>A</sub>	-40		+105	
ESD rating, Human Body Model(HBM)	U <sub>ESD</sub>		2		kV

**Isolation Characteristics**

Parameter	Symbol	Min	Unit	Comment
RMS Voltage for AC Insulation test 50/60Hz/1 min	V <sub>D</sub>	3	kV	
Through hole conductor isolation distance suggestion	D <sub>CP</sub>	5	mm	
Distance between source side lead and secondary side pin	D <sub>SS</sub>	6	mm	

**Electrical data MS20A(3% Accuracy)**

At Ta=25°C, Vc=5V, RL=100KΩ, unless otherwise noted

Parameter	Symbol	Min	Typ	Max	Unit	Comment
Primary nominal RMS current	I <sub>PN</sub>		10		A	
Primary current , measuring range	I <sub>PM</sub>		20		A	
Supply voltage	V <sub>C</sub>	4.75	5	5.25	V	
Number of primary turns	N <sub>P</sub>		1			
Resistance of primary jumper	R <sub>P</sub>		0.75		mΩ	@+25°C
Current consumption	I <sub>C</sub>		18	25	mA	
Output Voltage range @I <sub>PM</sub>	V <sub>O</sub>		2.5±2		V	
Temperature coefficient of V <sub>O</sub> @Ip=0A	TCV <sub>O</sub>		±200		PPM/K	@40~+85°C
Theoretical Sensitivity	G <sub>TH</sub>		100		mV/A	
Gain error	ε <sub>G</sub>		3		%	@+25°C
Temperature coefficient of Gain	TCG		±500		PPM/K	@-40~+85°C
Linearity error 0~I <sub>PM</sub>	ε <sub>L</sub>		0.4		% of I <sub>PM</sub>	
Magnetic offset voltage	V <sub>OM</sub>		10		mV	
Total Accuracy @I <sub>PM</sub>	X		3		% of V <sub>om</sub>	@+25°C
Frequency bandwidth(-3 dB)	BW		150		kHz	
Reaction time @10% of I <sub>PN</sub>	T <sub>RA</sub>		2.5		uS	
Reaction time @90% of I <sub>PN</sub>	T <sub>A</sub>		2.9		uS	

**Electrical data MS20B(5% Accuracy)**

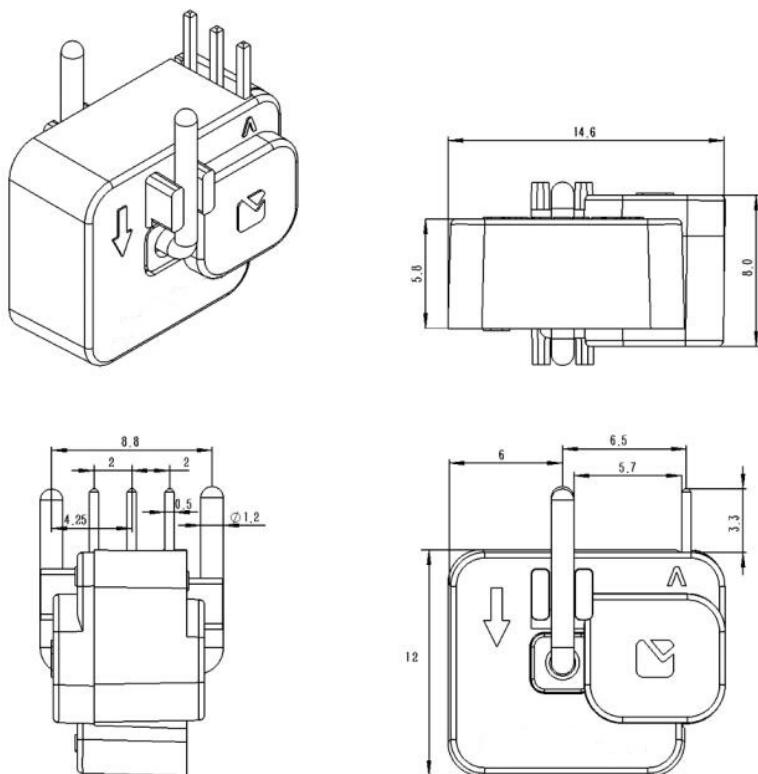
At Ta=25°C, Vc=5V, RL=100KΩ, unless otherwise noted

Parameter	Symbol	Min	Typ	Max	Unit	Comment
Primary nominal RMS current	I <sub>PN</sub>		10		A	
Primary current , measuring range	I <sub>PM</sub>		20		A	
Supply voltage	V <sub>C</sub>		5		V	
Number of primary turns	N <sub>P</sub>		1			
Resistance of primary jumper	R <sub>P</sub>		0.75		mΩ	@+25°C
Current consumption	I <sub>C</sub>		18	25	mA	
Output Voltage range @I <sub>PM</sub>	V <sub>O</sub>		2.5±2		V	
Temperature coefficient of V <sub>O</sub> @Ip=0A	TCV <sub>O</sub>		±300		PPM/K	@-40~+85°C
Theoretical Sensitivity	G <sub>TH</sub>		100		mV/A	
Gain error	ε <sub>G</sub>		5		%	@+25°C
Temperature coefficient of Gain	TCG		±500		PPM/K	@-40~+85°C
Linearity error 0~I <sub>PM</sub>	ε <sub>L</sub>		0.4		% of I <sub>PM</sub>	
Magnetic offset voltage	V <sub>OM</sub>		10		mV	

Total Accuracy @ $I_{PM}$	X	5	% of Vom	@+25°C
Frequency bandwidth(-3 dB)	BW	150	kHz	
Reaction time @10% of $I_{PN}$	$T_{RA}$	2.5	μS	
Reaction time @90% of $I_{PN}$	$T_A$	2.9	μS	

**Dimensions in MS series**

Mechanical Characteristics (Unit :mm, Tolerance in +-0.25)



strategic cooperation: Jiangsu China Sensor Technology Co., Ltd.

**Nanjing city Jiangning District Xingfa Road No. 99 211103.China**E-mail:master@csch.com.cn    [info@magtronworld.com](mailto:info@magtronworld.com)